

Title of Change:	Qualification of onsemi ISMF Fab (Malaysia) for Small Signal Transistor housed in SOT723 and SC74 package	
Proposed Changed Material First Ship Date:	01 Jun 2024 or earlier if approved by customer	
Current Material Last Order Date:	N/A Orders received after the Current Material Last Order Date expiration are to be considered as orders for new changed material as described in this PCN. Orders for current (unchanged) material after this date will be per mutual agreement and current material inventory availability.	
Current Material Last Delivery Date:	N/A The Current Material Last Delivery Date may be subject to change based on build and depletion of the current (unchanged) material inventory	
Product Category:	Active components – Discrete components	
Contact information:	Contact your local onsemi Sales Office or farrah.omar@onsemi.com	
PCN Samples Contact:	Contact your local onsemi Sales Office to place sample order. Sample requests are to be submitted no later than 45 days after publication of this change notification. Samples delivery timing will be subject to request date, sample quantity and special customer packing/label requirements.	
Additional Reliability Data:	Contact your local onsemi Sales Office or ChangKit.Mok@onsemi.com	
Type of Notification:	This is an Initial Product/Process Change Notification (IPCN) sent to customers. An IPCN is an advance notification about an upcoming change and contains general information regarding the change details and devices affected. It also contains the preliminary reliability qualification plan. The completed qualification and characterization data will be included in the Final Product/Process Change Notification (FPCN). This IPCN notification will be followed by a Final Product/Process Change Notification (FPCN) at least 6 months prior to implementation of the change. In case of questions, contact <pcn.support@onsemi.com>.</pcn.support@onsemi.com>	
Change Category		
Category	Type of Change	
Process - Wafer Production	New / change of metallization (specifically chip frontside), Move of all or part of wafer fab to a different location/site/subcontractor	
Process - Assembly	Change of lead frame finishing material / area (internal),	
Process - Assembly	Change of wire bonding	



#### **Description and Purpose:**

This is the Initial Notification by onsemi notifying customers of its plan to qualify small signal biploar junction transistor devices at onsemi ISMF fab (Malaysia) housed in SC74 and SOT723 package. onsemi ISMF fab has been an existing qualified manufacturing site for onsemi which is certified with IATF16949. onsemi ISMF fab qualification includes of changing top metal from AlSiCu to AlSi + TiW for devices in SC74 package.

In addition to this, onsemi Leshan (China) is making changes to the leadframe plating area from Ag plated to Cu plated as well as changing Au wire to Cu wire for devices in SC74 package.

	From	То	
JS Fou	ındry, Japan	onsemi ISMF, Malaysia	
SOT72	3: No change	SOT723: No change	
SC	74: AlSiCu	SC74: AlSi + TiW	
SOT72	3: No change	SOT723: No change	
SC74: /	Ag plated L/F	SC74: Cu plated L/F	
	0	SOT723: No change	
SC74: 1	3mil Au wire	SC74: 1.3mil Cu wire	
The device will be qualified and validated based on the same Product Specification. No anticipated impacts.			
onsemi Sites		External Foundry/Subcon Sites	
onsemi Leshan, China		None	
onsemi, ISMF Malaysia			
Changed material can be identified by lot code			
	SOT72 SC7 SOT72 SC74: / SOT72 SC74: 1 a result of this change Cost improvement The device will be qualified a	JS Foundry, Japan   SOT723: No change   SC74: AlSiCu   SOT723: No change   SC74: Ag plated L/F   SOT723: No change   SOT723: No change   SC74: 1.3mil Au wire   a result of this change   Cost improvement   The device will be qualified and validated based on the No anticipated impacts.   External Foundry/Sut	

# QV DEVICE NAME: NSV60101DMR6T1G

**RMS:** 88094 **PACKAGE:** SC74-6L

Test	Specification	Condition	Interval
High Temperature Reverse Bias	JESD22-A108	Ta=150°C, 100% max rated V	1008 hrs
High Temperature Storage Life	JESD22-A103	Ta= 150°C	1008 hrs
Preconditioning	J-STD-020 JESD-A113	MSL1 @260 °C	-
Intermittent Operating Life	MIL-STD-750 (M1037) AEC-Q101	Ta=+25°C, delta Tj=100°C On/off =2 min	15,000 cyc
Temperature Cycling	JESD22-A104	Ta= -55°C to +150°C	1000 сус
Highly Accelerated Stress Test	JESD22-A110	110°C, 85% RH, 17.7 psia, bias	264 hrs
Unbiased Highly Accelerated Stress Test	JESD22-A118	130°C, 85% RH, 18.8psig, unbiased	96 hrs
Resistance to Solder Heat	JESD22- B106	Ta = 265°C, 10 sec	-

# onsemi

Initial Product/Process Change Notification Document #:IPCN25507Z Issue Date:17 May 2023

# QV DEVICE NAME: NSVMMBT5401M3T5G RMS: 88095 PACKAGE: SOT723-3L

Test	Specification	Condition	Interval
High Temperature Reverse Bias	JESD22-A108	Ta=150°C, 100% max rated V	1008 hrs
High Temperature Storage Life	JESD22-A103	Ta= 150°C	1008 hrs
Preconditioning	J-STD-020 JESD-A113	MSL1 @260 °C	-
Intermittent Operating Life	MIL-STD-750 (M1037) AEC-Q101	Ta=+25°C, delta Tj=100°C On/off =2 min	15,000 cyc
Temperature Cycling	JESD22-A104	Ta= -55°C to +150°C	1000 сус
Highly Accelerated Stress Test	JESD22-A110	110°C, 85% RH, 17.7 psia, bias	264 hrs
Unbiased Highly Accelerated Stress Test	JESD22-A118	130°C, 85% RH, 18.8psig, unbiased	96 hrs
Resistance to Solder Heat	JESD22- B106	Ta = 265°C, 10 sec	-

Estimated date for qualification completion: WW44

## **Electrical Characteristics Summary:**

Electrical characteristics will be performed and updated per FPCN.

## List of Affected Parts:

**Note:** Only the standard (off the shelf) part numbers are listed in the parts list. Any custom parts affected by this PCN are shown in the customer specific PCN addendum in the PCN email notification, or on the <u>PCN Customized Portal</u>.

Current Part Number	New Part Number	Qualification Vehicle
NSV60101DMR6T2G	NA	NSV60101DMR6T1G
NSV60101DMR6T1G	NA	NSV60101DMR6T1G
NSVMMBT5401M3T5G	NA	NSVMMBT5401M3T5G